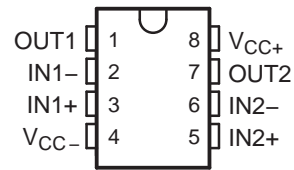


FEATURES

- Dual-Supply Operation . . . ± 5 V to ± 18 V
- Low Noise Voltage . . . $4.5 \text{ nV}/\sqrt{\text{Hz}}$
- Low Input Offset Voltage . . . 0.15 mV
- Low Total Harmonic Distortion . . . 0.002%
- High Slew Rate . . . $7 \text{ V}/\mu\text{s}$
- High-Gain Bandwidth Product . . . 16 MHz
- High Open-Loop AC Gain . . . 800 at 20 kHz
- Large Output-Voltage Swing . . . 14.1 V to -14.6 V
- Excellent Gain and Phase Margins

D (SOIC), DGK (MSOP), OR P (PDIP) PACKAGE
(TOP VIEW)



DESCRIPTION/ORDERING INFORMATION

The MC33078 is a bipolar dual operational amplifier with high-performance specifications for use in quality audio and data-signal applications. This device operates over a wide range of single- and dual-supply voltages and offers low noise, high-gain bandwidth, and high slew rate. Additional features include low total harmonic distortion, excellent phase and gain margins, large output voltage swing with no deadband crossover distortion, and symmetrical sink/source performance.

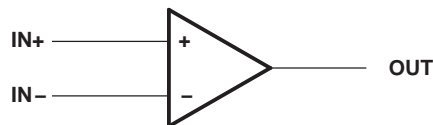
ORDERING INFORMATION

| T_A | PACKAGE ⁽¹⁾ | | ORDERABLE PART NUMBER | TOP-SIDE MARKING ⁽²⁾ |
|---------------|------------------------|--------------|-----------------------|---------------------------------|
| -40°C to 85°C | PDIP – P | Tube of 50 | MC33078P | MC33078P |
| | SOIC – D | Tube of 75 | MC33078D | M33078 |
| | | Reel of 2500 | MC33078DR | |
| | VSSOP/MSOP – DGK | Reel of 2500 | MC33078DGKR | MY_ |
| | | Reel of 250 | MC33078DGKT | |

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

(2) DGK: The actual top-side marking has one additional character that designates the assembly/test site.

SYMBOL (EACH AMPLIFIER)



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

| | | MIN | MAX | UNIT |
|-------------------------------------|---|-------------|--------------------------------------|------|
| V _{CC+} | Supply voltage ⁽²⁾ | | 18 | V |
| V _{CC-} | Supply voltage ⁽²⁾ | | -18 | V |
| V _{CC+} - V _{CC-} | Supply voltage | | 36 | V |
| | Input voltage, either input ⁽²⁾⁽³⁾ | | V _{CC+} or V _{CC-} | V |
| | Input current ⁽⁴⁾ | | ±10 | mA |
| | Duration of output short circuit ⁽⁵⁾ | | Unlimited | |
| θ _{JA} | Package thermal impedance, junction to free air ⁽⁶⁾⁽⁷⁾ | D package | 97 | °C/W |
| | | DGK package | 172 | |
| | | P package | 85 | |
| T _J | Operating virtual junction temperature | | 150 | °C |
| T _{stg} | Storage temperature range | -65 | 150 | °C |

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, except differential voltages, are with respect to the midpoint between V_{CC+} and V_{CC-}.
- (3) The magnitude of the input voltage must never exceed the magnitude of the supply voltage.
- (4) Excessive input current will flow if a differential input voltage in excess of approximately 0.6 V is applied between the inputs, unless some limiting resistance is used.
- (5) The output may be shorted to ground or either power supply. Temperature and/or supply voltages must be limited to ensure the maximum dissipation rating is not exceeded.
- (6) Maximum power dissipation is a function of T_{J(max)}, θ_{JA}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is P_D = (T_{J(max)} - T_A)/θ_{JA}. Operating at the absolute maximum T_J of 150°C can affect reliability.
- (7) The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions

| | | MIN | MAX | UNIT |
|------------------|--------------------------------------|-----|-----|------|
| V _{CC-} | Supply voltage | -5 | -18 | V |
| V _{CC+} | | 5 | 18 | |
| T _A | Operating free-air temperature range | -40 | 85 | °C |

Electrical Characteristics

$V_{CC-} = -15\text{ V}$, $V_{CC+} = 15\text{ V}$, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

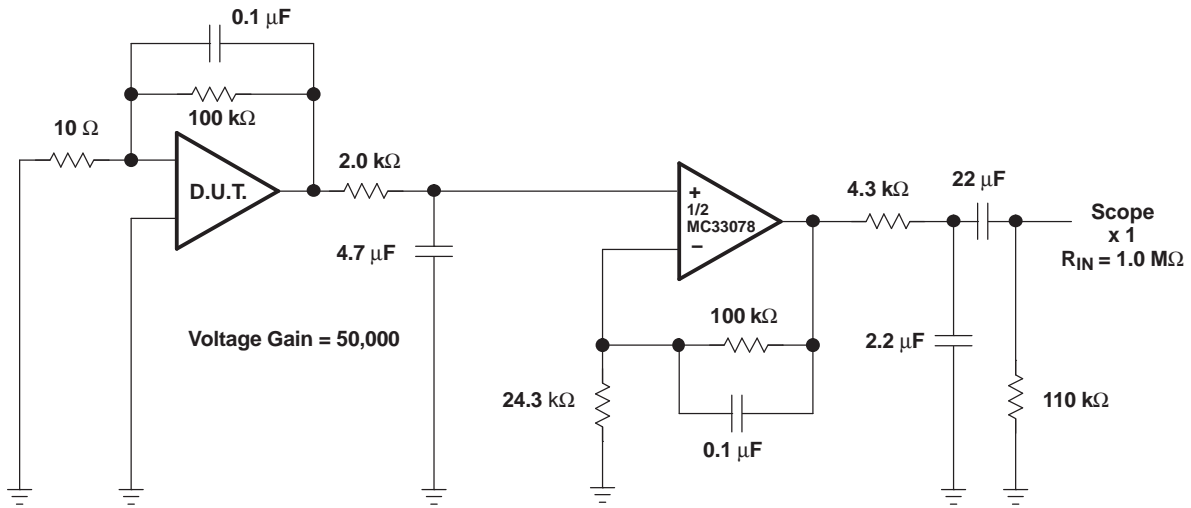
| PARAMETER | | TEST CONDITIONS | | MIN | TYP | MAX | UNIT |
|-----------------|---|---|---|-----------|----------|-------|------------------------------|
| V_{IO} | Input offset voltage | $V_O = 0$, $R_S = 10\ \Omega$, $V_{CM} = 0$ | $T_A = 25^\circ\text{C}$ | 0.15 | 2 | | mV |
| | | | $T_A = -40^\circ\text{C}$ to 85°C | | | 3 | |
| αV_{IO} | Input offset voltage temperature coefficient | $V_O = 0$, $R_S = 10\ \Omega$, $V_{CM} = 0$ | $T_A = -40^\circ\text{C}$ to 85°C | | 2 | | $\mu\text{V}/^\circ\text{C}$ |
| I_{IB} | Input bias current | $V_O = 0$, $V_{CM} = 0$ | $T_A = 25^\circ\text{C}$ | | 300 | 750 | nA |
| | | | $T_A = -40^\circ\text{C}$ to 85°C | | | 800 | |
| I_{IO} | Input offset current | $V_O = 0$, $V_{CM} = 0$ | $T_A = 25^\circ\text{C}$ | | 25 | 150 | nA |
| | | | $T_A = -40^\circ\text{C}$ to 85°C | | | 175 | |
| V_{ICR} | Common-mode input voltage range | $\Delta V_{IO} = 5\text{ mV}$, $V_O = 0$ | | ± 13 | ± 14 | | V |
| A_{VD} | Large-signal differential voltage amplification | $R_L \geq 2\text{ k}\Omega$, $V_O = \pm 10\text{ V}$ | $T_A = 25^\circ\text{C}$ | 90 | 110 | | dB |
| | | | $T_A = -40^\circ\text{C}$ to 85°C | 85 | | | |
| V_{OM} | Maximum output voltage swing | $V_{ID} = \pm 1\text{ V}$ | $R_L = 600\ \Omega$ | V_{OM+} | | 10.7 | V |
| | | | | V_{OM-} | | -11.9 | |
| | | | $R_L = 2\text{ k}\Omega$ | V_{OM+} | 13.2 | 13.8 | |
| | | | | V_{OM-} | -13.2 | -13.7 | |
| | | | $R_L = 10\text{ k}\Omega$ | V_{OM+} | 13.5 | 14.1 | |
| | | | | V_{OM-} | -14 | -14.6 | |
| CMMR | Common-mode rejection ratio | $V_{IN} = \pm 13\text{ V}$ | | 80 | 100 | | dB |
| $k_{SVR}^{(1)}$ | Supply-voltage rejection ratio | $V_{CC+} = 5\text{ V}$ to 15 V , $V_{CC-} = -5\text{ V}$ to -15 V | | 80 | 105 | | dB |
| I_{OS} | Output short-circuit current | $ V_{ID} = 1\text{ V}$, Output to GND | Source current | 15 | 29 | | mA |
| | | | Sink current | -20 | -37 | | |
| I_{CC} | Supply current (per channel) | $V_O = 0$ | $T_A = 25^\circ\text{C}$ | | 2.05 | 2.5 | mA |
| | | | $T_A = -40^\circ\text{C}$ to 85°C | | | 2.75 | |

(1) Measured with $V_{CC\pm}$ differentially varied at the same time

Operating Characteristics

$V_{CC-} = -15\text{ V}$, $V_{CC+} = 15\text{ V}$, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | | MIN | TYP | MAX | UNIT |
|-----------|--------------------------------|--|-----------------------|-----|-------|-----|------------------------|
| SR | Slew rate at unity gain | $A_{VD} = 1$, $V_{IN} = -10\text{ V}$ to 10 V , $R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$ | | 5 | 7 | | V/ μs |
| GBW | Gain bandwidth product | $f = 100\text{ kHz}$ | | 10 | 16 | | MHz |
| B_1 | Unity gain frequency | Open loop | | | 9 | | MHz |
| G_m | Gain margin | $R_L = 2\text{ k}\Omega$ | $C_L = 0\text{ pF}$ | | -11 | | dB |
| | | | $C_L = 100\text{ pF}$ | | -6 | | |
| Φ_m | Phase margin | $R_L = 2\text{ k}\Omega$ | $C_L = 0\text{ pF}$ | | 55 | | deg |
| | | | $C_L = 100\text{ pF}$ | | 40 | | |
| | Amp-to-amp isolation | $f = 20\text{ Hz}$ to 20 kHz | | | -120 | | dB |
| | Power bandwidth | $V_O = 27\text{ V}_{(PP)}$, $R_L = 2\text{ k}\Omega$, $\text{THD} \leq 1\%$ | | | 120 | | kHz |
| THD | Total harmonic distortion | $V_O = 3\text{ V}_{rms}$, $A_{VD} = 1$, $R_L = 2\text{ k}\Omega$, $f = 20\text{ Hz}$ to 20 kHz | | | 0.002 | | % |
| Z_o | Open-loop output impedance | $V_O = 0$, $f = 9\text{ MHz}$ | | | 37 | | Ω |
| r_{id} | Differential input resistance | $V_{CM} = 0$ | | | 175 | | k Ω |
| C_{id} | Differential input capacitance | $V_{CM} = 0$ | | | 12 | | pF |
| V_n | Equivalent input noise voltage | $f = 1\text{ kHz}$, $R_S = 100\ \Omega$ | | | 4.5 | | nV/ $\sqrt{\text{Hz}}$ |
| I_n | Equivalent input noise current | $f = 1\text{ kHz}$ | | | 0.5 | | pA/ $\sqrt{\text{Hz}}$ |

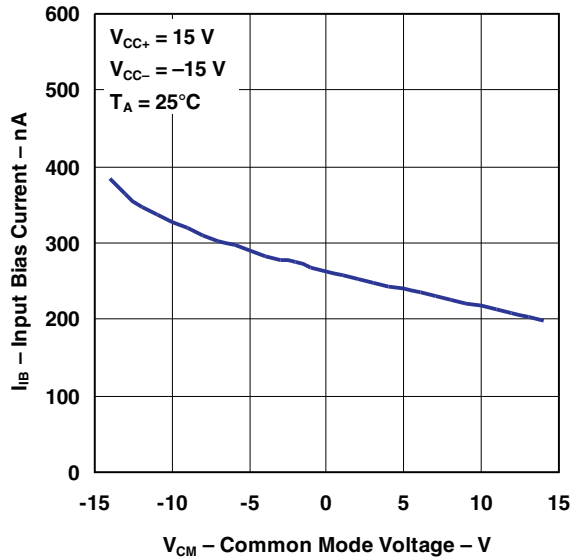


NOTE: All capacitors are non-polarized.

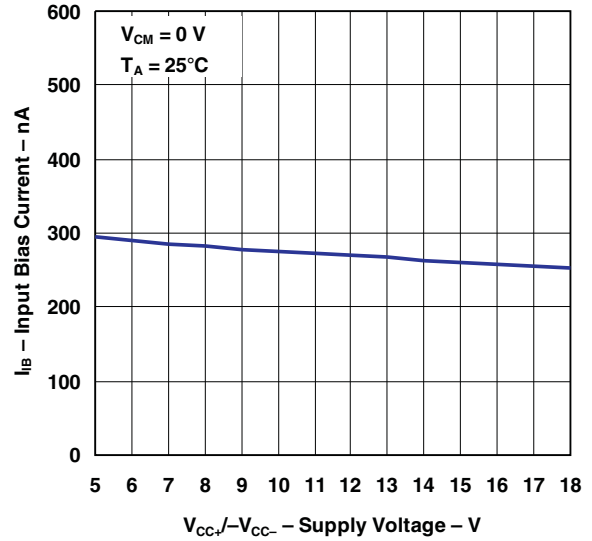
Figure 1. Voltage Noise Test Circuit (0.1 Hz to 10 Hz)

TYPICAL CHARACTERISTICS

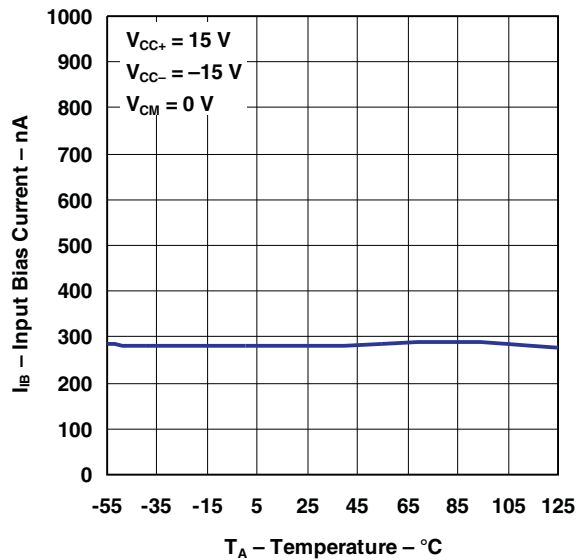
INPUT BIAS CURRENT
 VS
COMMON-MODE VOLTAGE



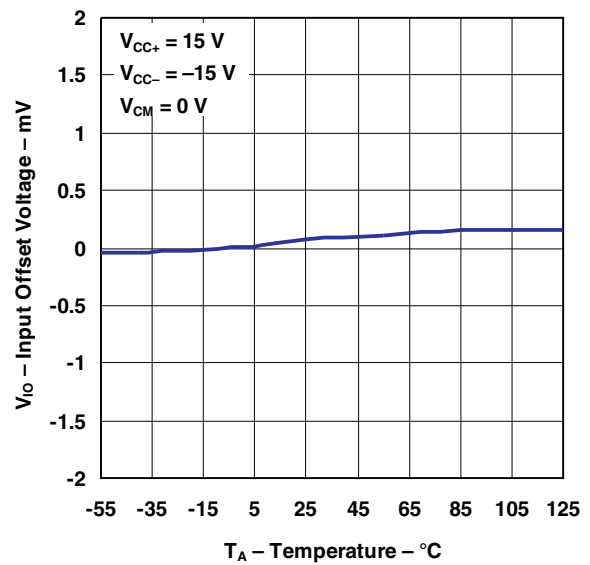
INPUT BIAS CURRENT
 VS
SUPPLY VOLTAGE



INPUT BIAS CURRENT
 VS
TEMPERATURE

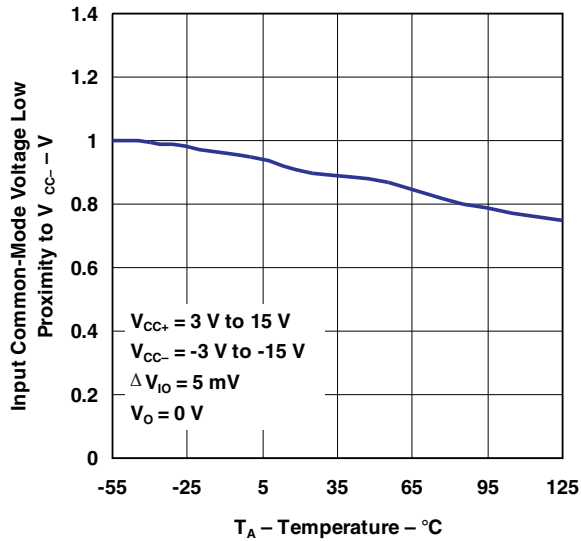


INPUT OFFSET VOLTAGE
 VS
TEMPERATURE

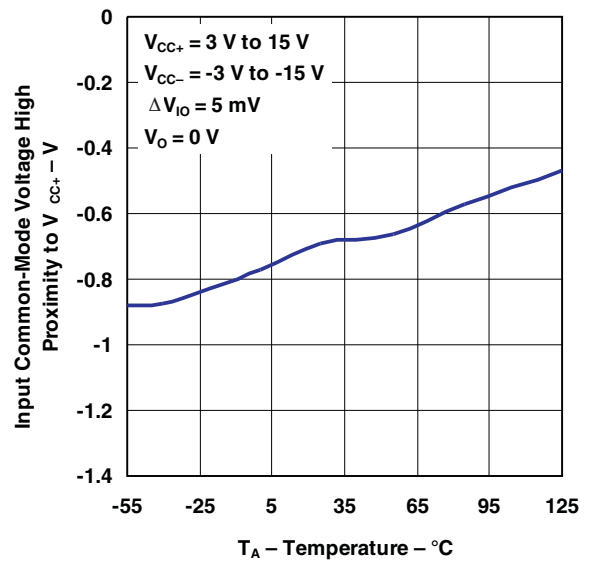


TYPICAL CHARACTERISTICS (continued)

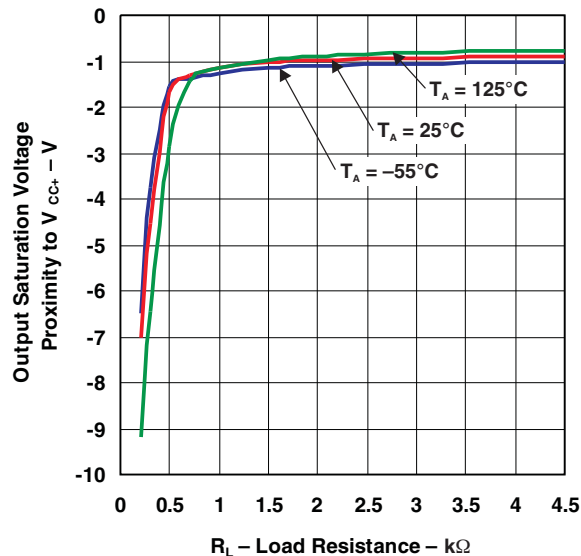
INPUT COMMON-MODE VOLTAGE
 LOW PROXIMITY TO V_{CC-}
 VS
 TEMPERATURE



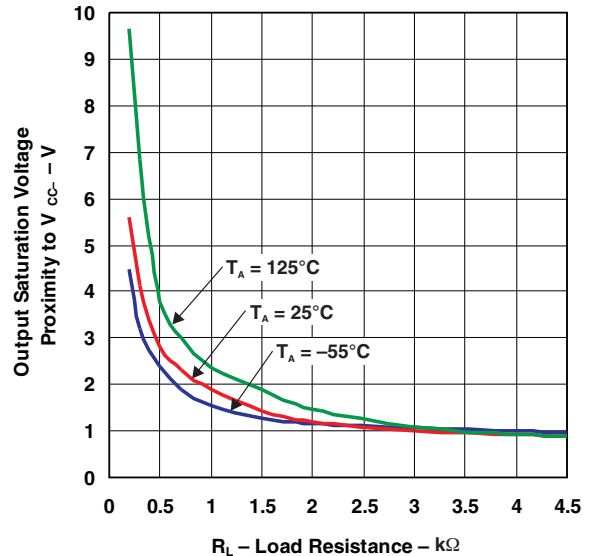
INPUT COMMON-MODE VOLTAGE
 HIGH PROXIMITY TO V_{CC+}
 VS
 TEMPERATURE



OUTPUT SATURATION VOLTAGE PROXIMITY TO V_{CC+}
 VS
 LOAD RESISTANCE

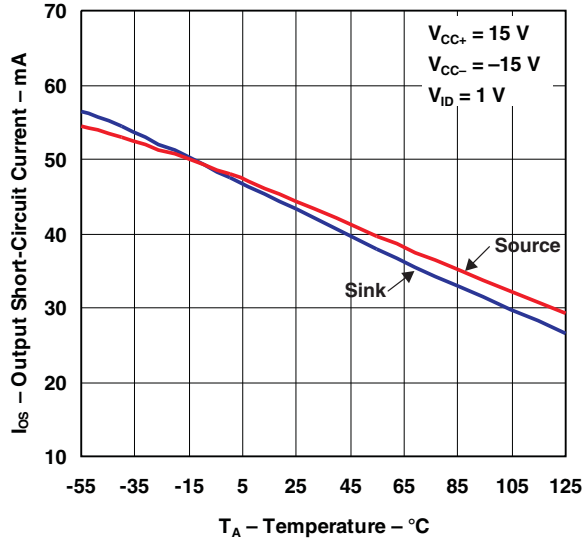


OUTPUT SATURATION VOLTAGE PROXIMITY TO V_{CC-}
 VS
 LOAD RESISTANCE

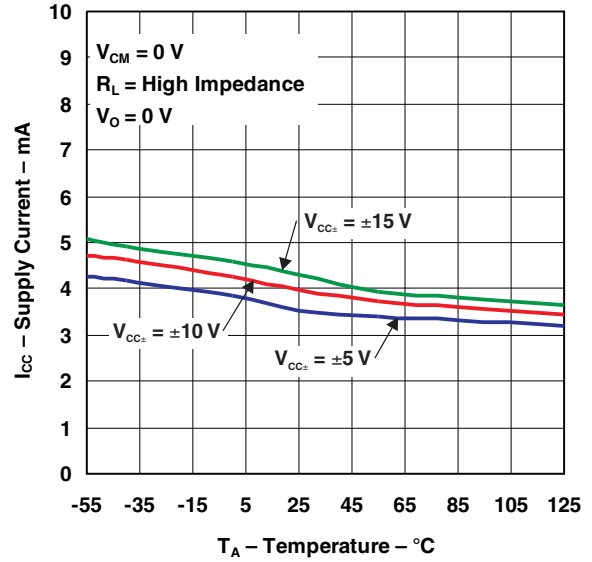


TYPICAL CHARACTERISTICS (continued)

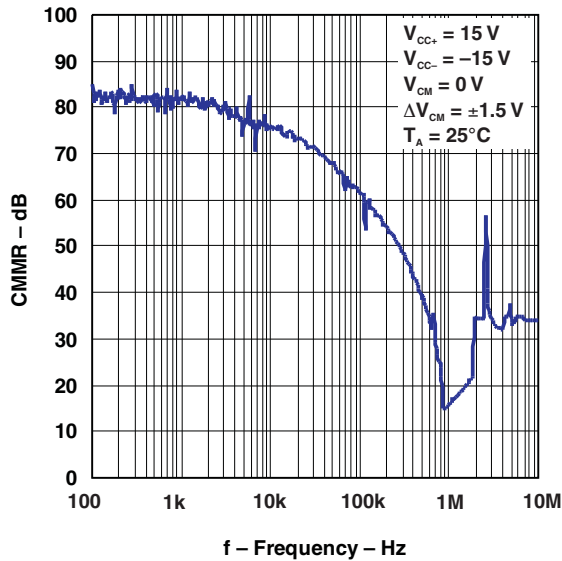
**OUTPUT SHORT-CIRCUIT CURRENT
VS
TEMPERATURE**



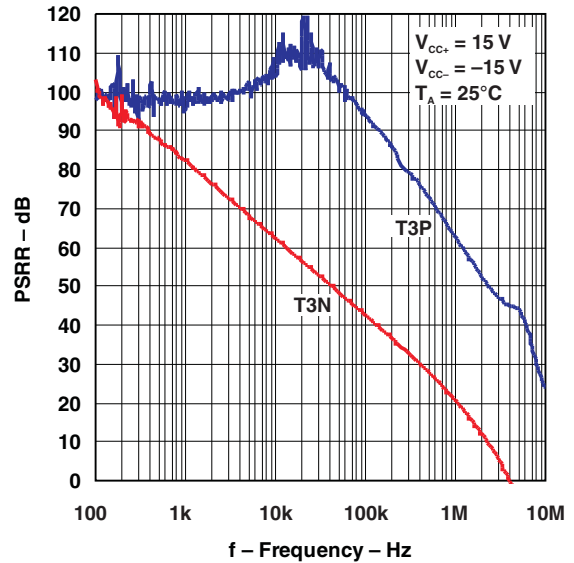
**SUPPLY CURRENT
VS
TEMPERATURE**



**CMRR
VS
FREQUENCY**

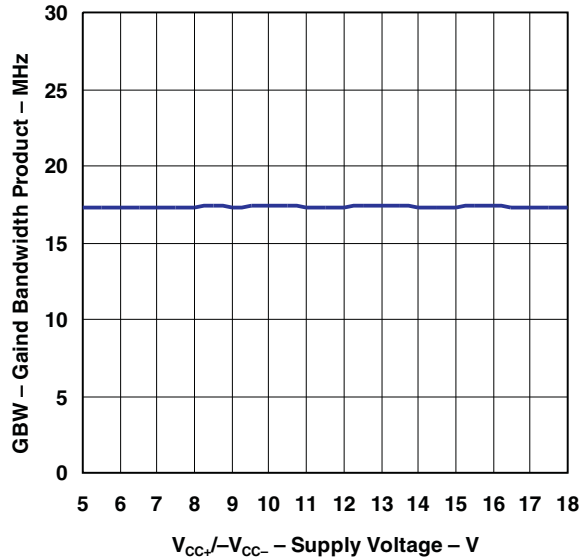


**PSSR
VS
FREQUENCY**

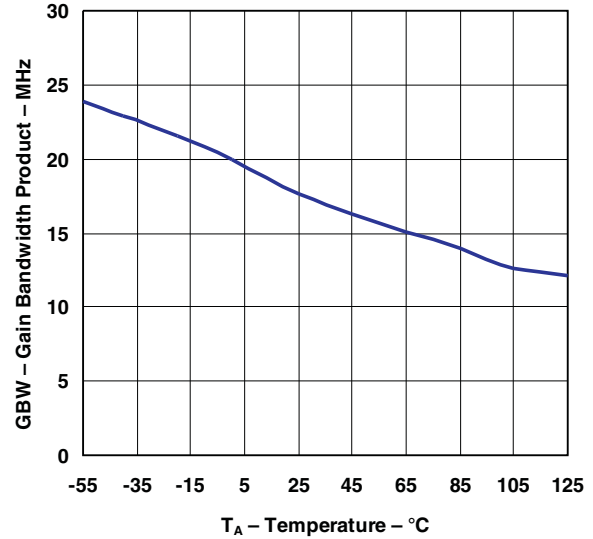


TYPICAL CHARACTERISTICS (continued)

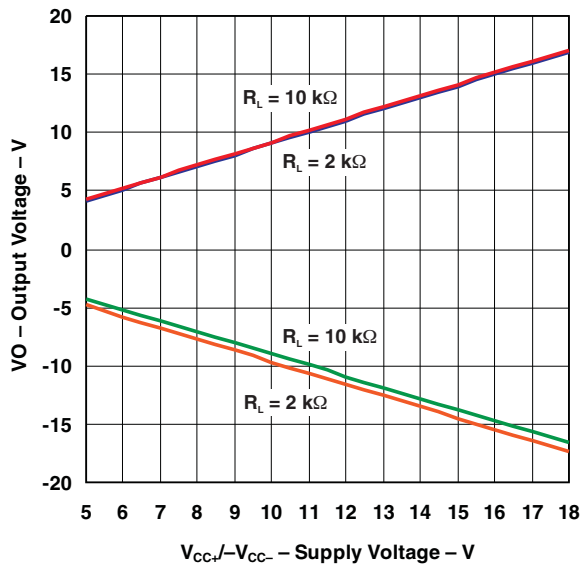
GAIN BANDWIDTH PRODUCT
 VS
 SUPPLY VOLTAGE



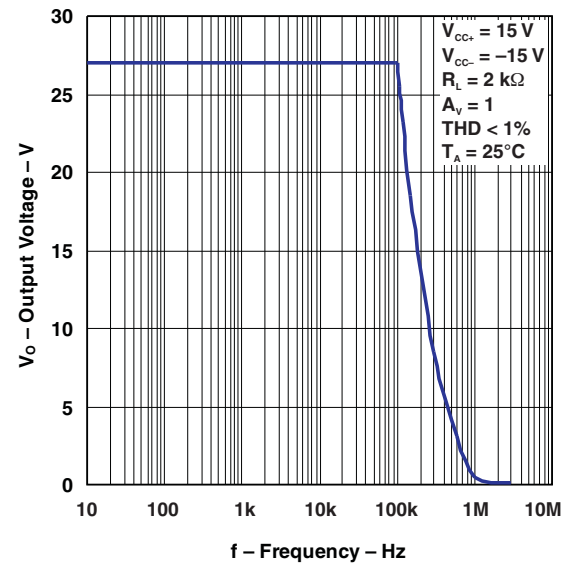
GAIN BANDWIDTH PRODUCT
 VS
 TEMPERATURE



OUTPUT VOLTAGE
 VS
 SUPPLY VOLTAGE

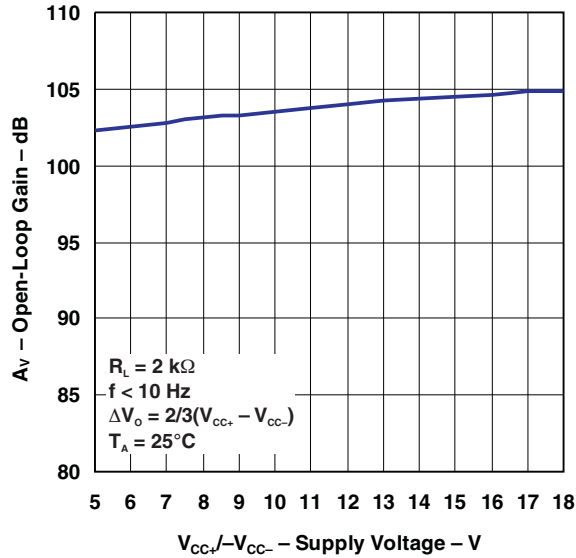


OUTPUT VOLTAGE
 VS
 FREQUENCY

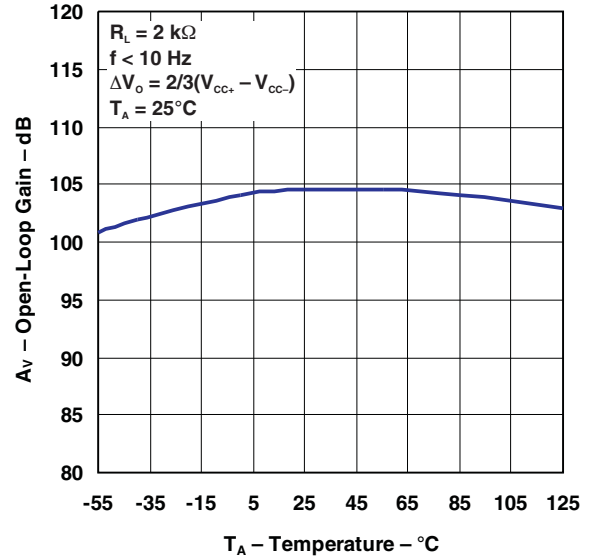


TYPICAL CHARACTERISTICS (continued)

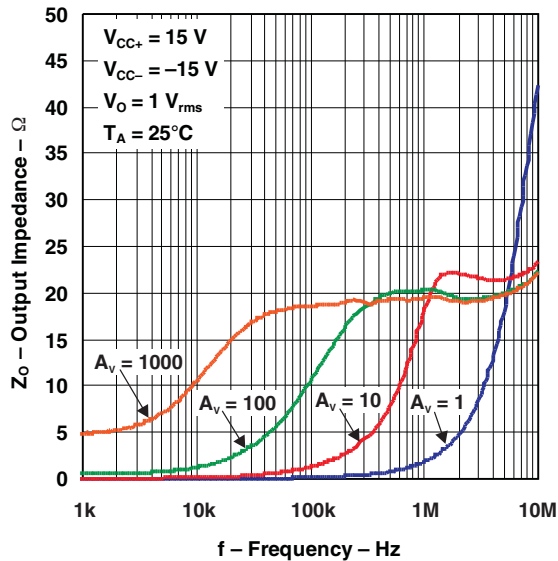
**OPEN-LOOP GAIN
VS
SUPPLY VOLTAGE**



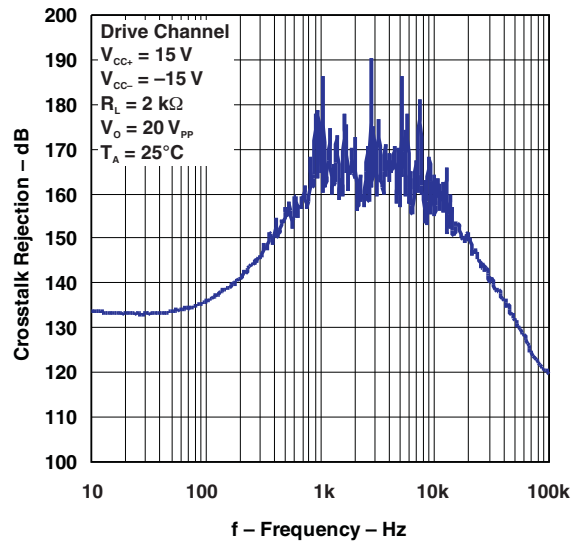
**OPEN-LOOP GAIN
VS
TEMPERATURE**



**OUTPUT IMPEDANCE
VS
FREQUENCY**

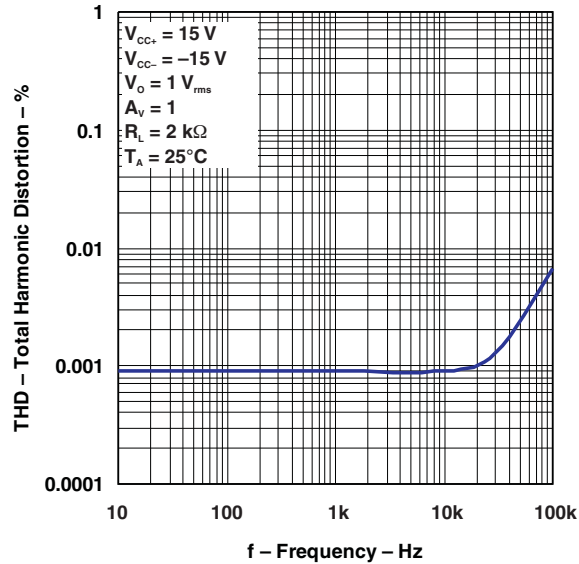


**CROSSTALK REJECTION
VS
FREQUENCY**

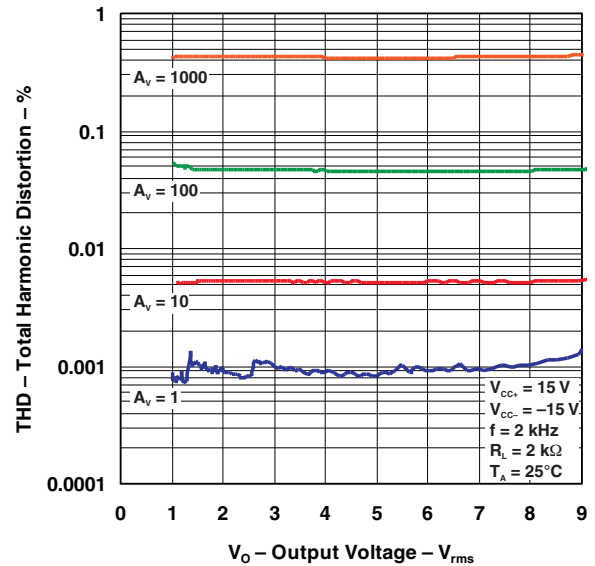


TYPICAL CHARACTERISTICS (continued)

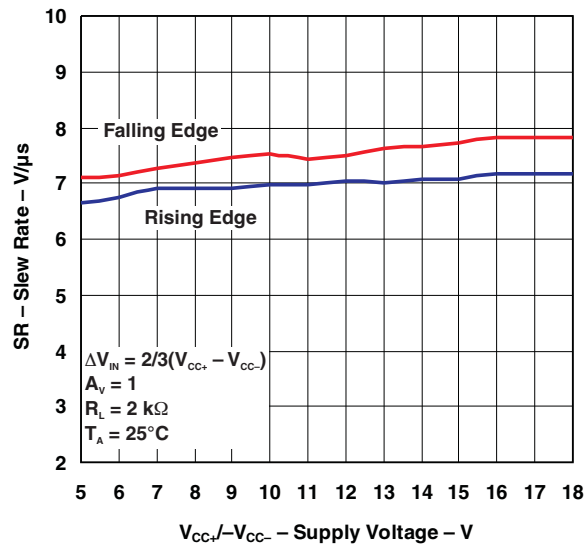
TOTAL HARMONIC DISTORTION
 VS
 FREQUENCY



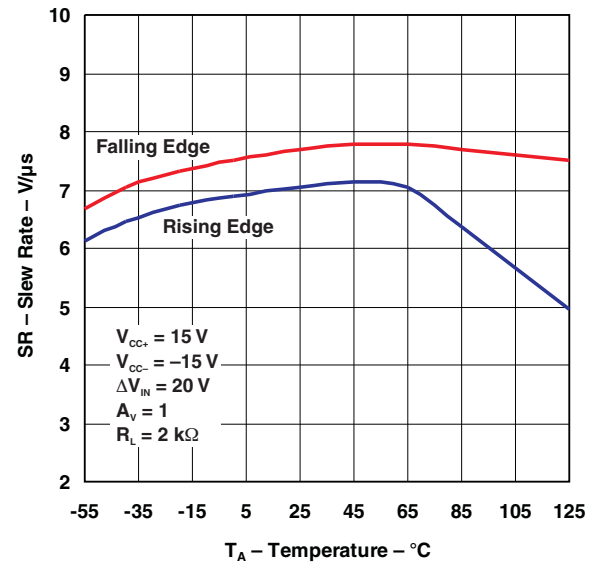
TOTAL HARMONIC DISTORTION
 VS
 OUTPUT VOLTAGE



SLEW RATE
 VS
 SUPPLY VOLTAGE

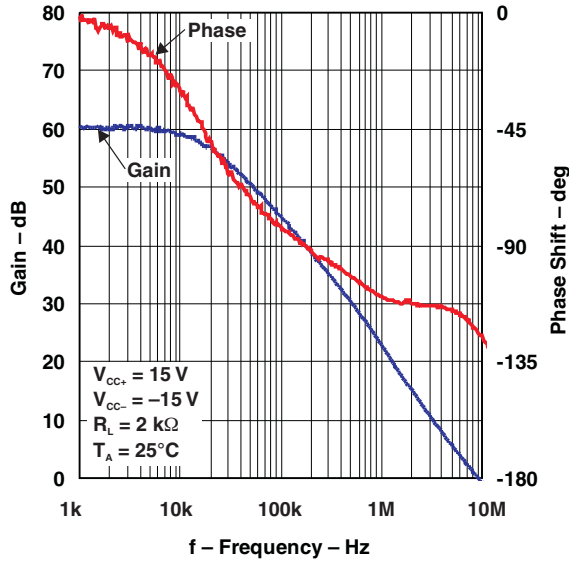


SLEW RATE
 VS
 TEMPERATURE

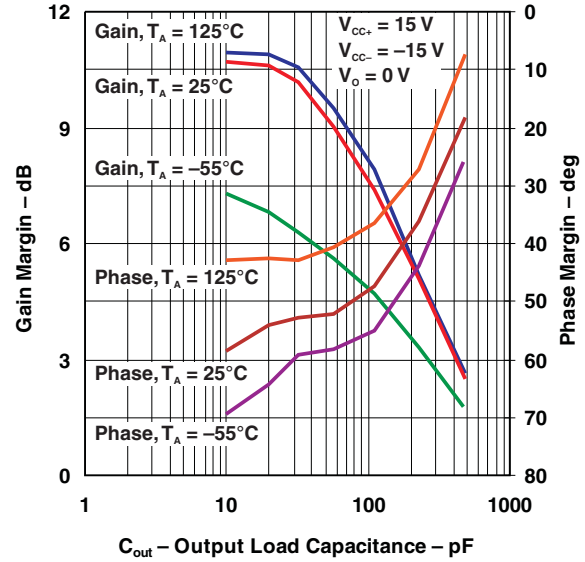


TYPICAL CHARACTERISTICS (continued)

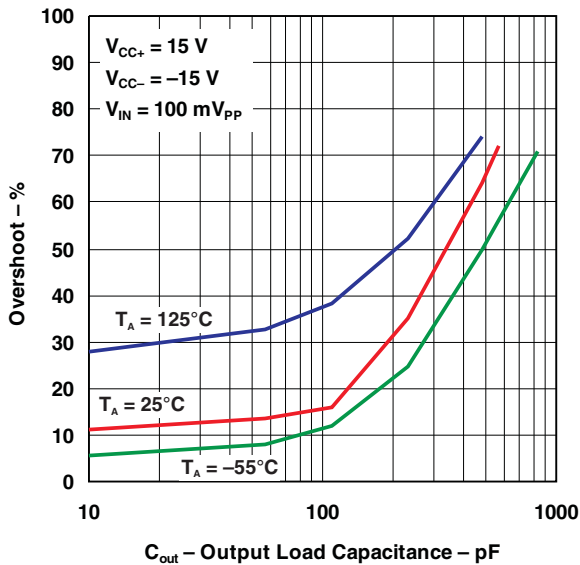
GAIN AND PHASE
VS
FREQUENCY



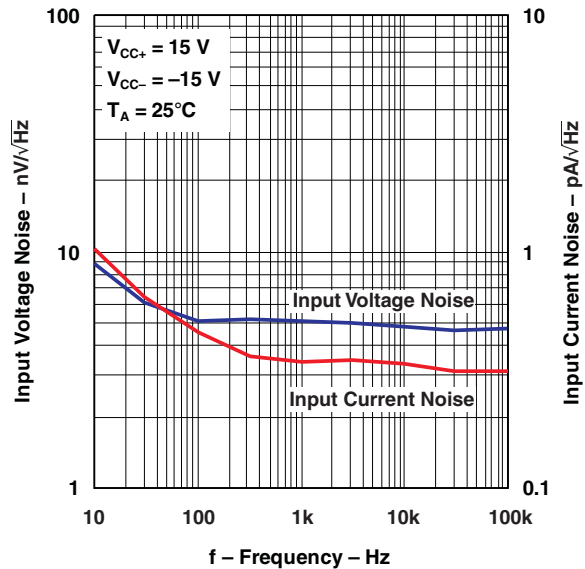
GAIN AND PHASE MARGIN
VS
OUTPUT LOAD CAPACITANCE



OVERSHOOT
VS
OUTPUT LOAD CAPACITANCE

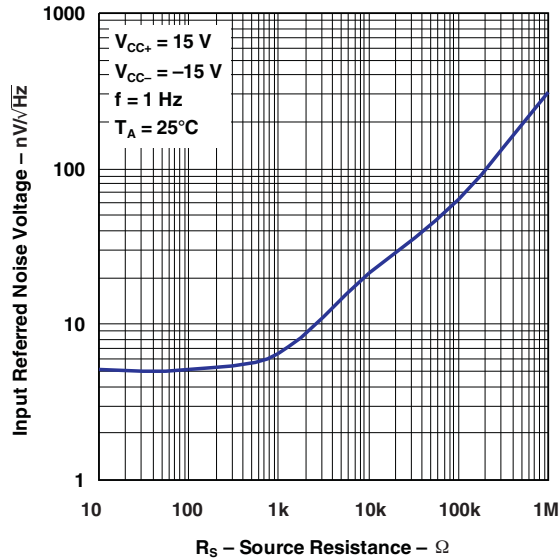


INPUT VOLTAGE AND CURRENT NOISE
VS
FREQUENCY

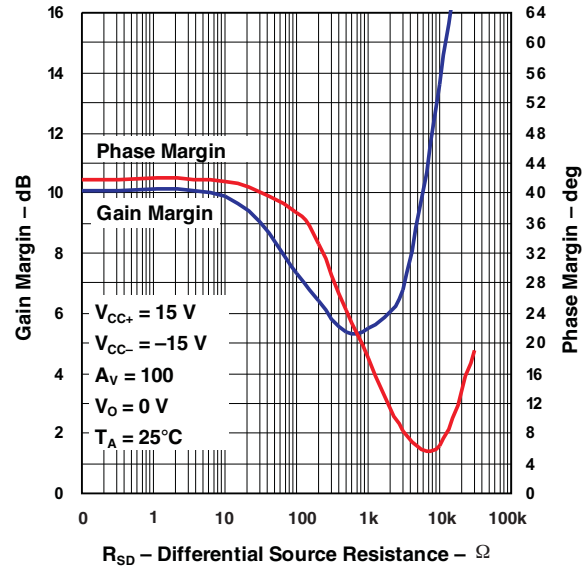


TYPICAL CHARACTERISTICS (continued)

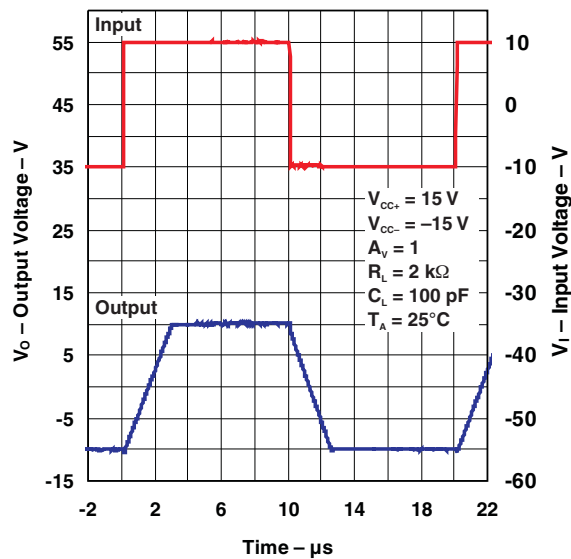
INPUT REFERRED NOISE VOLTAGE
 VS
 SOURCE RESISTANCE



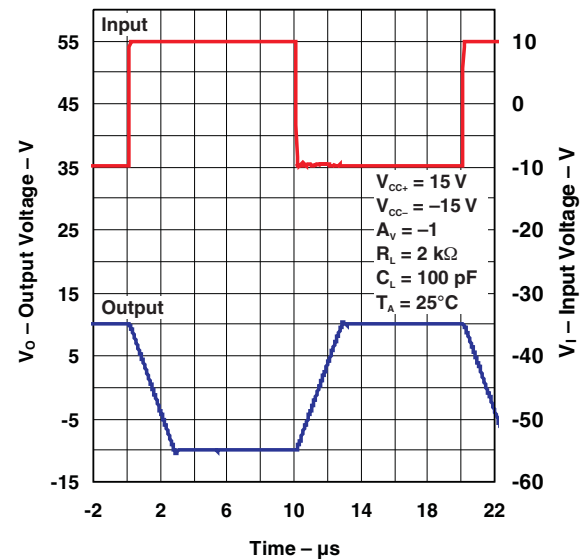
GAIN AND PHASE MARGIN
 VS
 DIFFERENTIAL SOURCE RESISTANCE



LARGE SIGNAL TRANSIENT RESPONSE
 (AV = 1)

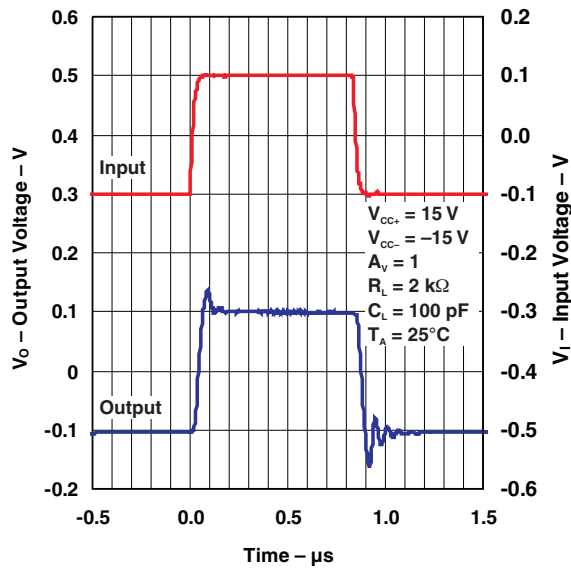


LARGE SIGNAL TRANSIENT RESPONSE
 (AV = -1)

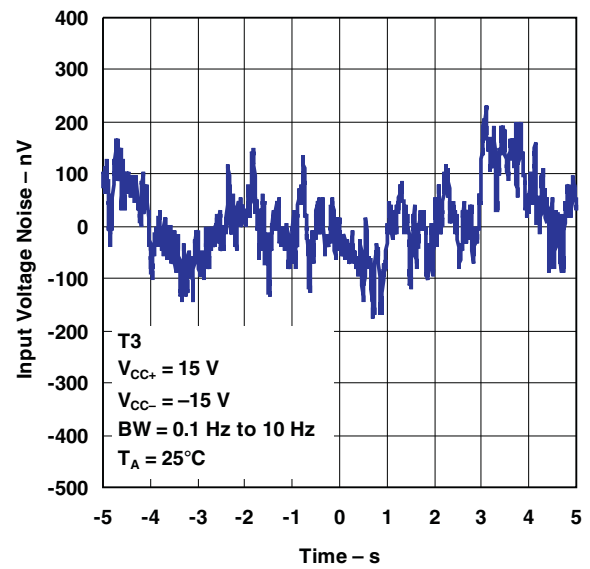


TYPICAL CHARACTERISTICS (continued)

SMALL SIGNAL TRANSIENT RESPONSE



LOW_FREQUENCY NOISE



APPLICATION INFORMATION

Output Characteristics

All operating characteristics are specified with 100-pF load capacitance. The MC33078 can drive higher capacitance loads. However, as the load capacitance increases, the resulting response pole occurs at lower frequencies, causing ringing, peaking, or oscillation. The value of the load capacitance at which oscillation occurs varies from lot to lot. If an application appears to be sensitive to oscillation due to load capacitance, adding a small resistance in series with the load should alleviate the problem (see Figure 2).

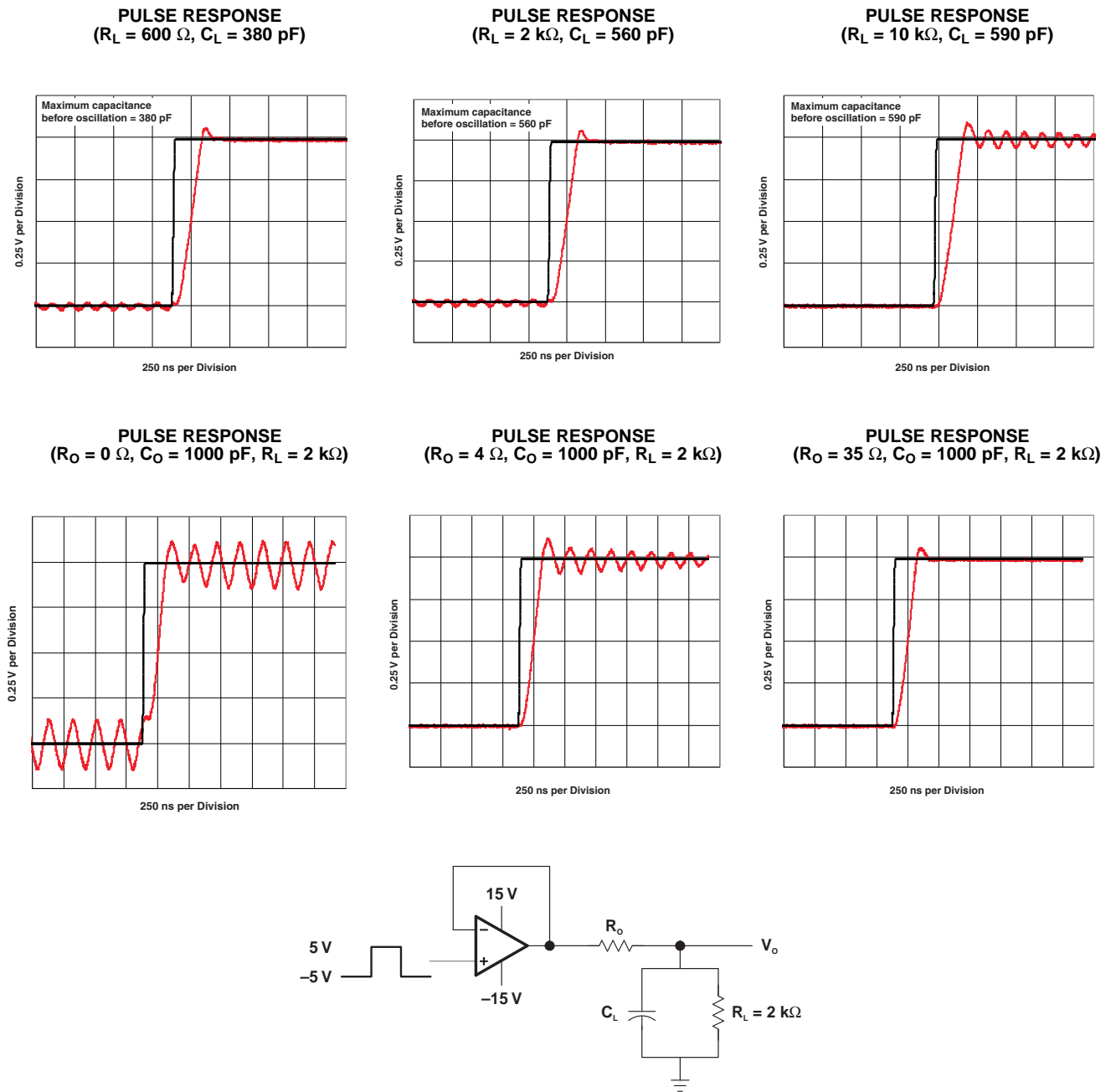


Figure 2. Output Characteristics

PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead finish/ Ball material (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|-----------------|------|-------------|-----------------|--------------------------------------|----------------------|--------------|-------------------------|-------------------------|
| MC33078D | ACTIVE | SOIC | D | 8 | 75 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | M33078 | Samples |
| MC33078DG4 | ACTIVE | SOIC | D | 8 | 75 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | M33078 | Samples |
| MC33078DGKR | ACTIVE | VSSOP | DGK | 8 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | MYU | Samples |
| MC33078DGKRG4 | ACTIVE | VSSOP | DGK | 8 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | MYU | Samples |
| MC33078DGKT | ACTIVE | VSSOP | DGK | 8 | 250 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | MYU | Samples |
| MC33078DR | ACTIVE | SOIC | D | 8 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | M33078 | Samples |
| MC33078DRE4 | ACTIVE | SOIC | D | 8 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | M33078 | Samples |
| MC33078P | ACTIVE | PDIP | P | 8 | 50 | RoHS & Green | NIPDAU | N / A for Pkg Type | -40 to 85 | MC33078P | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF MC33078 :

- Enhanced Product : [MC33078-EP](#)

NOTE: Qualified Version Definitions:

- Enhanced Product - Supports Defense, Aerospace and Medical Applications

TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| MC33078DGKR | VSSOP | DGK | 8 | 2500 | 330.0 | 12.4 | 5.3 | 3.3 | 1.3 | 8.0 | 12.0 | Q1 |
| MC33078DGKT | VSSOP | DGK | 8 | 250 | 180.0 | 12.4 | 5.3 | 3.3 | 1.3 | 8.0 | 12.0 | Q1 |
| MC33078DR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| MC33078DR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|-------------|--------------|-----------------|------|------|-------------|------------|-------------|
| MC33078DGKR | VSSOP | DGK | 8 | 2500 | 346.0 | 346.0 | 35.0 |
| MC33078DGKT | VSSOP | DGK | 8 | 250 | 200.0 | 183.0 | 25.0 |
| MC33078DR | SOIC | D | 8 | 2500 | 853.0 | 449.0 | 35.0 |
| MC33078DR | SOIC | D | 8 | 2500 | 340.5 | 336.1 | 25.0 |

TUBE


*All dimensions are nominal

| Device | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (μm) | B (mm) |
|------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| MC33078D | D | SOIC | 8 | 75 | 506.6 | 8 | 3940 | 4.32 |
| MC33078D | D | SOIC | 8 | 75 | 507 | 8 | 3940 | 4.32 |
| MC33078DG4 | D | SOIC | 8 | 75 | 506.6 | 8 | 3940 | 4.32 |
| MC33078DG4 | D | SOIC | 8 | 75 | 507 | 8 | 3940 | 4.32 |
| MC33078P | P | PDIP | 8 | 50 | 506 | 13.97 | 11230 | 4.32 |



D0008A

PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed $.006$ [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

EXAMPLE BOARD LAYOUT

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
 EXPOSED METAL SHOWN
 SCALE:8X



SOLDER MASK DETAILS

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NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

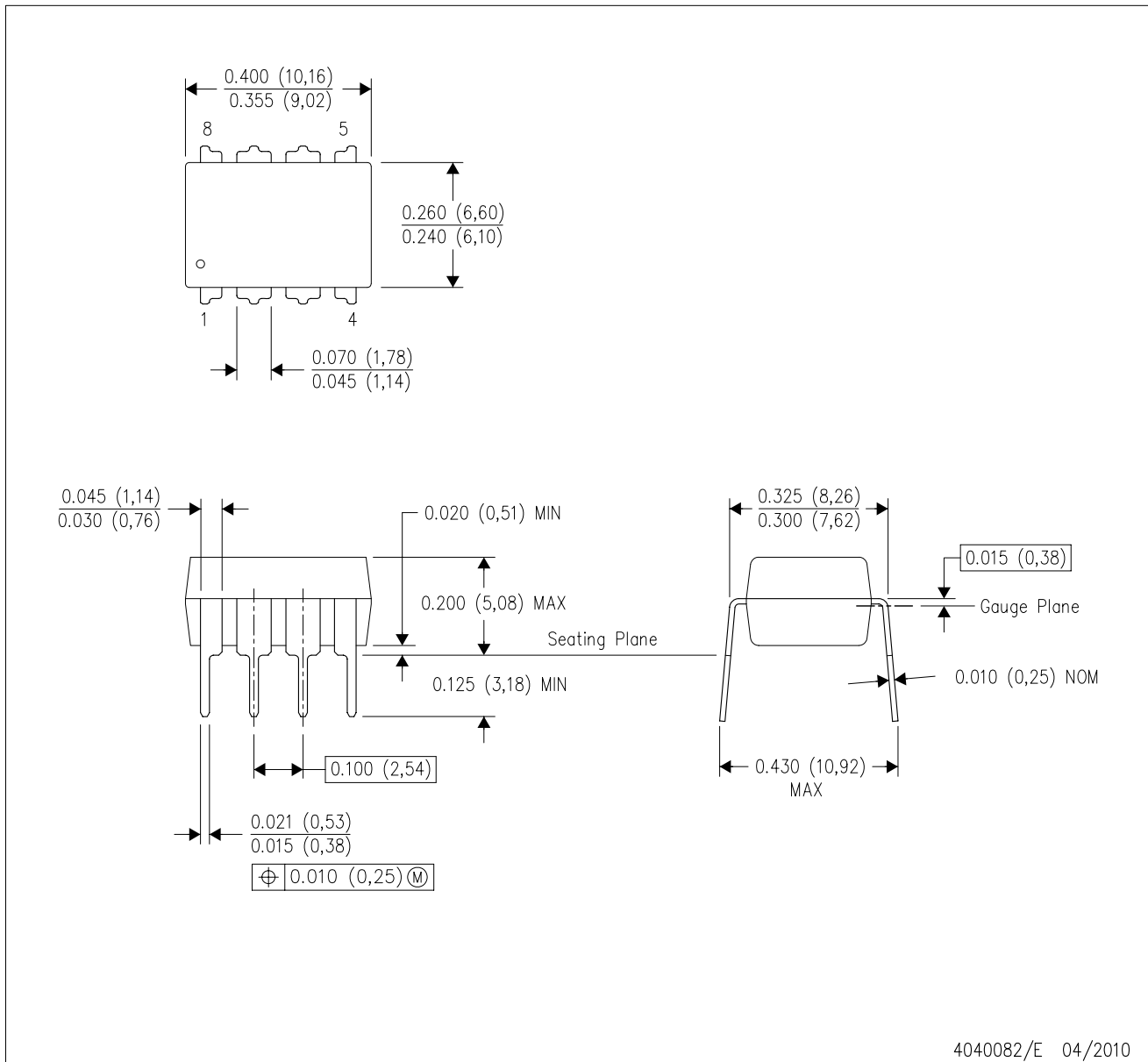
4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MS-001 variation BA.



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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